



1N5817 - 1N5819

Incorporated

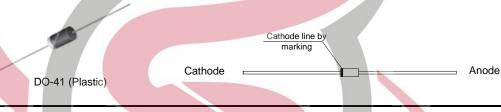
1.0A SCHOTTKY BARRIER RECTIFIER

Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Application
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: DO-41
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Tin. Plated Leads Solderable per MIL-STD-202. Method 208 (e3)
- Polarity: Cathode Band
- Marking: Type Number and Date Code
- Weight: 0.3 grams (Approximate)



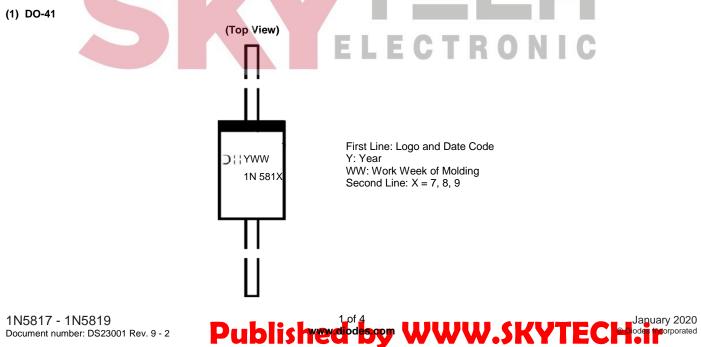
Ordering Information (Note 3)

Part Number	Packaging	Shipping
1N5817-B	DO-41 (Plastic)	1 <mark>K/Bu</mark> lk
1N5817-T	DO-41 (Plastic)	5K/Tape & Reel, 13 inch
1N5818-T	DO-41 (Plastic)	5K/Tape <mark>& Ree</mark> l, 13 inch
1N5819-B	DO-41 (Plastic)	1K/Bulk
1N5819-T	DO-41 (Plastic)	5K/Tape & Reel, 13 inch

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free

3. For packaging details, visit our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





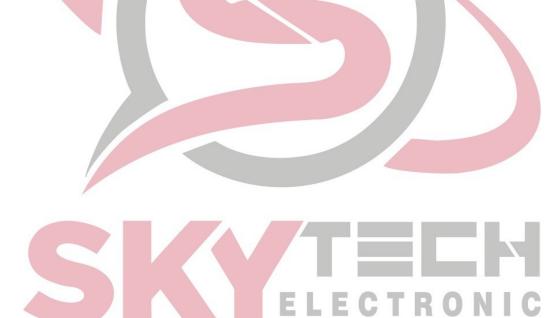
Maximum Ratings and Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

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For ca	pacitive	load.	derate	current b	ov 20%.	

Characteristic		Symbol	1N5817	1N5818	1N5819	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		Vrrm Vrwm Vr	20	30	40	V
RMS Reverse Voltage		VR(RMS)	14	21	28	V
Average Rectified Output Current (Note 4) @ TL = +90°C		lo	1.0			А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load		I _{FSM}	25			А
Forward Voltage (Note 5)	@ IF = 1.0A @ IF = 3.0A	Vfm	0.450 0.750	0.550 0.875	0.60 0.90	V
Peak Reverse Leakage Current at Rated DC Blocking Voltage (Note 5)	@ T _A = +25°C @ T _A = +100°C	IRM		1.0 10		mA
Typical Total Capacitance (Note 6)		Ст		110		pF
Typical Thermal Resistance Junction to Lead (Note 7)		R _{0JL}	15 50			°C/W
Typical Thermal Resistance Junction to Ambient		R _{0JA}				C/VV
Operating and Storage Temperature Range		TJ, TSTG	-65 to +125			°C

Notes: 4. Measured at ambient temperature at a distance of 9.5mm from the case.
5. Short duration test pulse used to minimize self-heating effect.
6. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
7. Thermal resistance from junction to lead vertical P.C.B. mounted, 0.375" (9.5mm) lead length with 1.5 x 1.5" (38 x 38mm) copper pads.

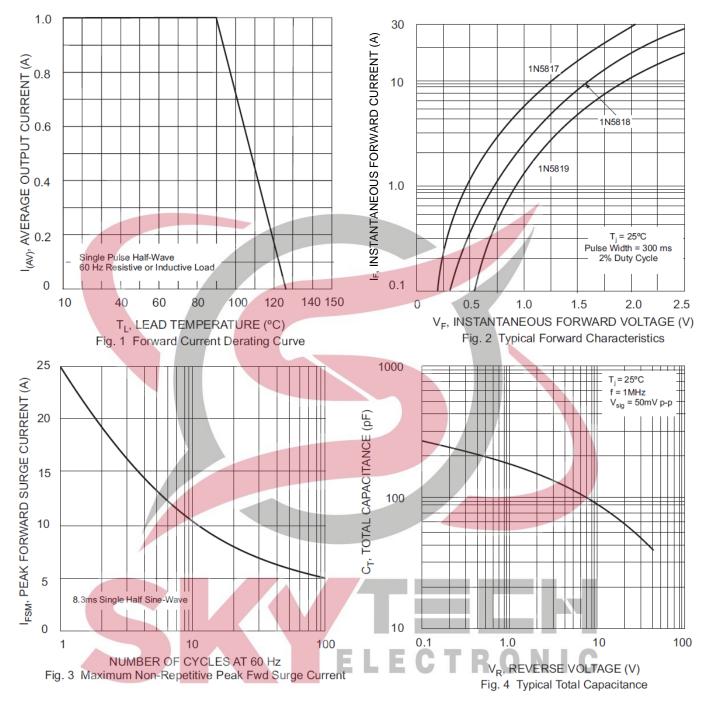






January 2020

odes incorporated



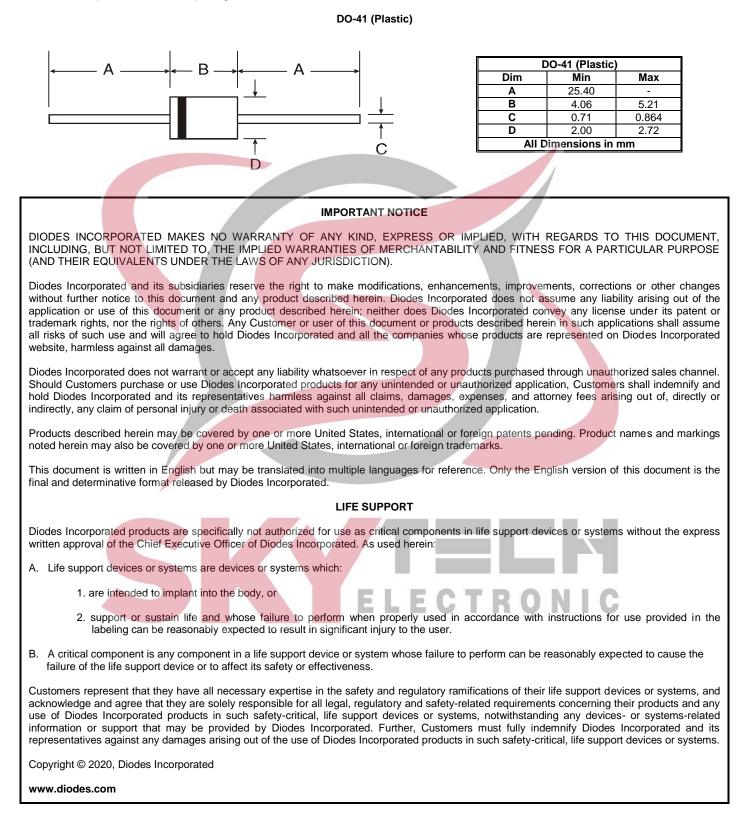
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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



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